



30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17501Q5A

FEATURES

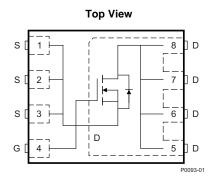
- Ultralow Q_q and Q_{qd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

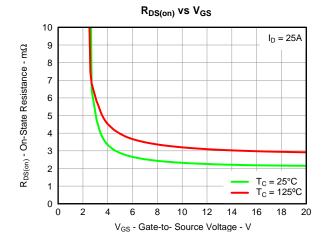
APPLICATIONS

- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Optimized for Synchronous FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

$T_A = 25$ °C	unless otherwise stated	TYPICAL VA	UNIT	
V_{DS}	Drain to Source Voltage	30	V	
Q_g	Gate Charge Total (4.5V) 13.2		nC	
Q_{gd}	Gate Charge Gate to Drain	3.5		nC
D	Drain to Source On Resistance	V _{GS} = 4.5V 3		mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V 2.		mΩ
V _{GS(th)}	Threshold Voltage	1.3	V	

ORDERING INFORMATION

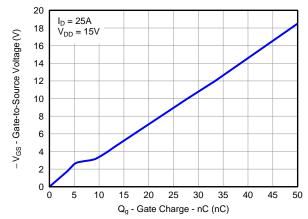
Device	Package	Media	Qty	Ship	
CSD17501Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	٧
V_{GS}	Gate to Source Voltage	±20	>
	Continuous Drain Current, T _C = 25°C	100	Α
I _D	Continuous Drain Current ⁽¹⁾	28	Α
I_{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	187	Α
P _D	Power Dissipation ⁽¹⁾	3.2	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 90A$, $L = 0.1mH$, $R_G = 25\Omega$	405	mJ

- (1) Typical $R_{\theta JA} = 39^{\circ} \text{C/W}$ on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%

GATE CHARGE



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics				,	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = 250\mu A$	30			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 24V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = 20V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	1	1.3	1.8	V
D	Drain to Source On Registeres	V _{GS} = 4.5V, I _{DS} = 25A		3	3.7	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _{DS} = 25A		2.4	2.9	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 25A		110		S
Dynamic	: Characteristics					
C _{iss}	Input Capacitance			2040	2630	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz	135		1700	pF
C _{rss}	Reverse Transfer Capacitance	1 - 11/11/2		66	85	pF
R _G	Series Gate Resistance			1.3	2.6	Ω
Qg	Gate Charge Total (4.5V)			13.2	17	nC
Q _{gd}	Gate Charge Gate to Drain	V 45V I 25A		3.5		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 15V, I_{DS} = 25A$		5.4		nC
Q _{g(th)}	Gate Charge at Vth			2.9		nC
Q _{oss}	Output Charge	V _{DS} = 13.7V, V _{GS} = 0V		35		nC
t _{d(on)}	Turn On Delay Time			10.4		ns
t _r	Rise Time	$V_{DS} = 15V, V_{GS} = 4.5V,$		17		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 25A, R_G = 2\Omega$		18		ns
t _f	Fall Time			7.9		ns
Diode Cl	haracteristics					
V _{SD}	Diode Forward Voltage	$I_{SD} = 25A, V_{GS} = 0V$		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V 40.7V L 05.4 dVd. 000.4 /		46		nC
t _{rr}	Reverse Recovery Time	$V_{DD} = 13.7V$, $I_F = 25A$, di/dt = 300A/ μ s		32		ns

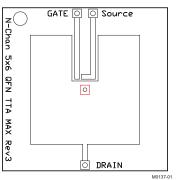
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

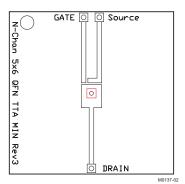
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			1	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			49	°C/W

 ⁽¹⁾ R_{θJC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
 (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.





Max $R_{\theta JA} = 49^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 114^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

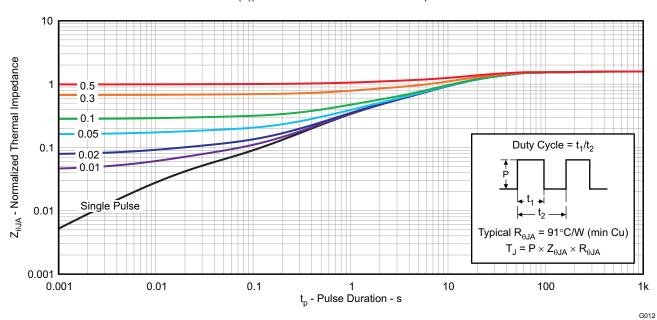


Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

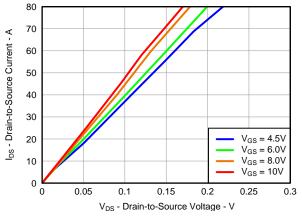


Figure 2. Saturation Characteristics

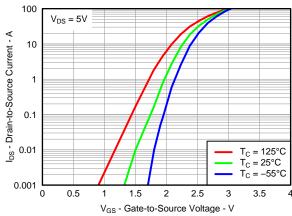


Figure 3. Transfer Characteristics

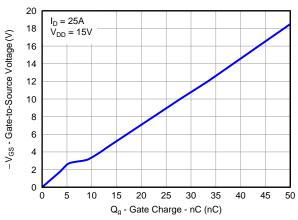


Figure 4. Gate Charge

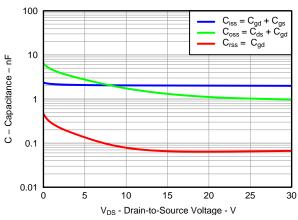


Figure 5. Capacitance

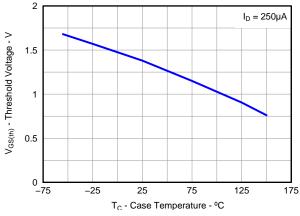


Figure 6. Threshold Voltage vs. Temperature

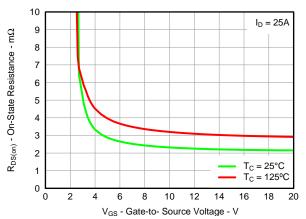


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

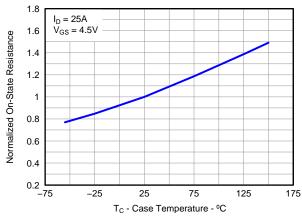


Figure 8. Normalized On-State Resistance vs. Temperature

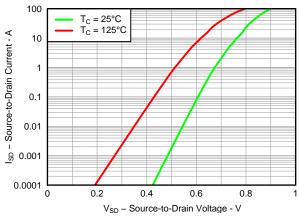


Figure 9. Typical Diode Forward Voltage

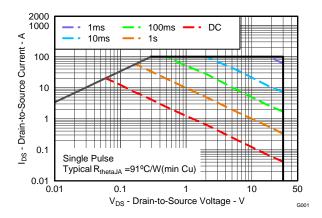


Figure 10. Maximum Safe Operating Area

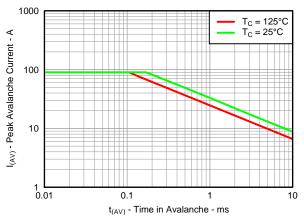


Figure 11. Single Pulse Unclamped Inductive Switching

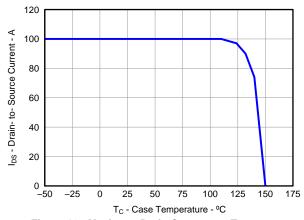
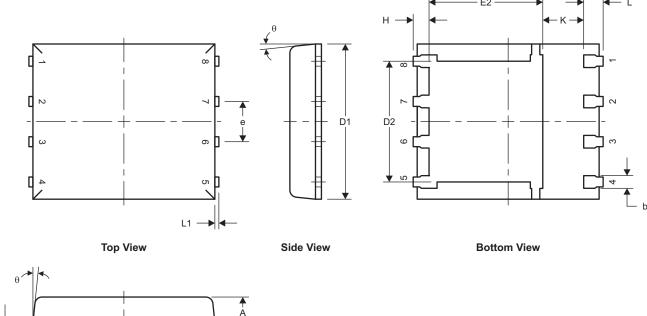


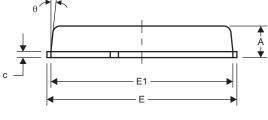
Figure 12. Maximum Drain Current vs. Temperature



MECHANICAL DATA

Q5A Package Dimensions





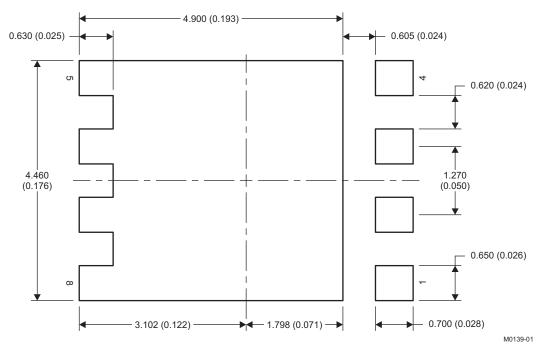
Front View

M0135-01

DIM		MILLIMETERS					
DIM	MIN	NOM	MAX				
А	0.90	1.00	1.10				
b	0.33	0.41	0.51				
С	0.20	0.25	0.34				
D1	4.80	4.90	5.00				
D2	3.61	3.81	4.02				
Е	5.90	6.00	6.10				
E1	5.70	5.75	5.80				
E2	3.38	3.58	3.78				
е	1.17	1.27	1.37				
Н	0.41	0.56	0.71				
K	1.10						
L	0.51	0.61	0.71				
L1	0.06	0.13	0.20				
θ	0°		12°				

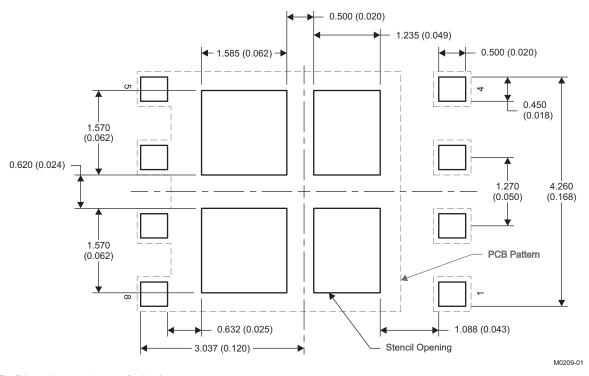


Recommended PCB Pattern



NOTE: Dimensions are in mm (inches).

Stencil Recommendation

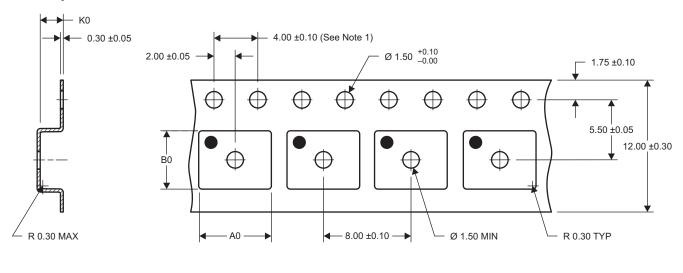


NOTE: Dimensions are in mm (inches).

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.



Q5A Tape and Reel Information



 $A0 = 6.50 \pm 0.10$ $B0 = 5.30 \pm 0.10$ $K0 = 1.40 \pm 0.10$

M0138-01

- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
 - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
 - 3. Material: black static-dissipative polystyrene
 - 4. All dimensions are in mm (unless otherwise specified)
 - 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

REVISION HISTORY

Changes from Original (December 2010) to Revision A Page • Changed V_{GS} in the Abs Max Ratings table From: +20/-12V To: $\pm 20V$ 1 • Changed the I_{GSS} Test Conditions From: $V_{GS} = 20V + 20/-12$ To: $V_{GS} = 20$ V 2 Changes from Revision A (July 2011) to Revision B Page • Changed Figure 10 5

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17501Q5A	SON	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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*All dimensions are nominal

I	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	CSD17501Q5A	SON	DQJ	8	2500	340.0	340.0	38.0	

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